

## 1-Line Ultra Low Capacitance Bi-directional TVS Diode

**Features**

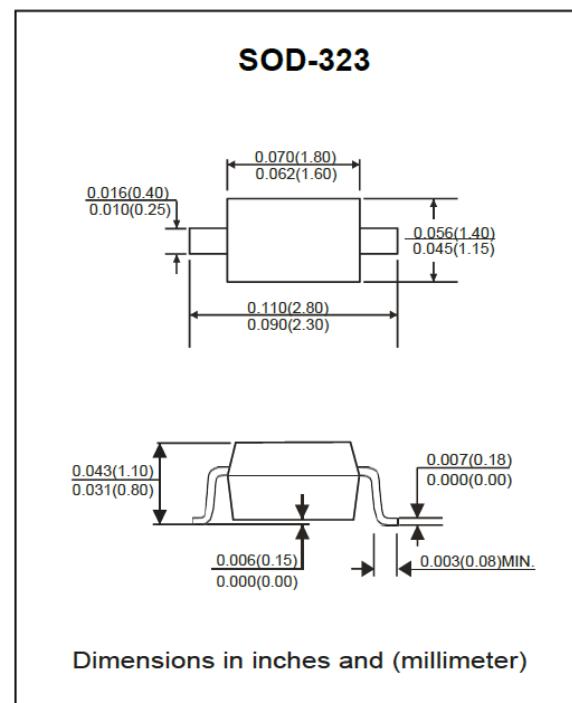
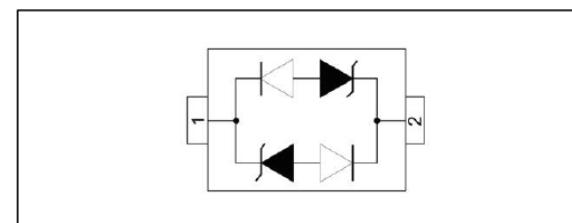
- IEC 61000-4-2 (ESD)  $\pm 30\text{kV}$  (air),  $\pm 30\text{kV}$  (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 21A (8/20 $\mu\text{s}$ )
- 340W peak pulse power (8/20 $\mu\text{s}$ )
- Protects one power line or data line
- Operating voltage: 3.3V
- Low clamping voltage
- Low leakage current
- Response Time is < 1 ns

**Applications**

- Portable Instrumentation
- Ethernet 10/100/1000
- Wireless Systems
- Smart Phones
- Peripherals
- USB Interface

**Mechanical Characteristics**

- Package: SOD-323
- Flammability Rating: UL 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- High temperature soldering guaranteed: 260°C/10s
- Material: Halogen free

**Circuit Diagram****Absolute Maximum Ratings ( $T_A = 25^\circ\text{C}$  Unless otherwise noted)**

Parameter	Symbol	Value	Unit
Peak Pulse Power ( $t_p = 8/20\mu\text{s}$ )	$P_{PP}$	340	W
ESD per IEC 61000-4-2 (Air)	$V_{ESD}$	$\pm 30$	kV
ESD per IEC 61000-4-2 (Contact)		$\pm 30$	kV
Operating Temperature Range	$T_{OPT}$	-55 to + 125	°C
Storage Temperature Range	$T_{STG}$	-55 to + 150	°C
Lead Soldering Temperature	$T_L$	260	°C

Electrical Parameters ( $T_A = 25^\circ C$ Unless otherwise noted)	
Symbol	Parameter
$I_{PP}$	Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Reverse Stand-Off Voltage
$I_R$	Reverse Leakage Current @ $V_{RWM}$
$V_{PT}$	Punch-through Breakdown Voltage @ $I_{PT}$
$V_{SB}$	Snap-Back Voltage @ $I_{SB}$
$I_{SB}$	Snap-Back Current
$I_{PT}$	Test Current

Electrical Characteristics ( $T_A = 25^\circ C$ Unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Reverse Standoff Voltage	$V_{RWM}$				3.3	V
Punch-Through Voltage	$V_{PT}$	$I_{PT} = 2\mu A$	3.5			V
Snap-Back Voltage	$V_{SB}$	$I_{SB} = 50mA$	2.8			V
Reverse leakage current	$I_R$	$V_{RWM} = 3.3V$			0.2	$\mu A$
Clamping Voltage	$V_C$	$I_{PP} = 1A, t_p = 8/20\mu s$			5.0	V
Clamping Voltage	$V_C$	$I_{PP} = 21A, t_p = 8/20\mu s$			16	V
Junction capacitance	$C_J$	$V_R = 0V, f = 1MHz$		1.0		pF

### Typical Performance Characteristics ( $T_A = 25^\circ\text{C}$ Unless otherwise noted)

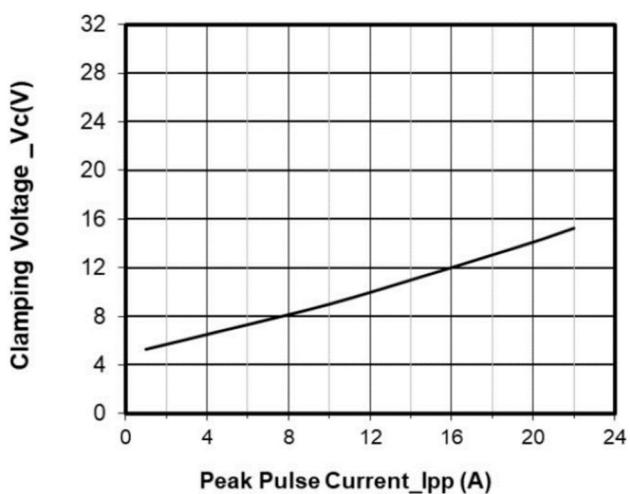


Figure 1: Clamping Voltage vs. Peak Pulse Current

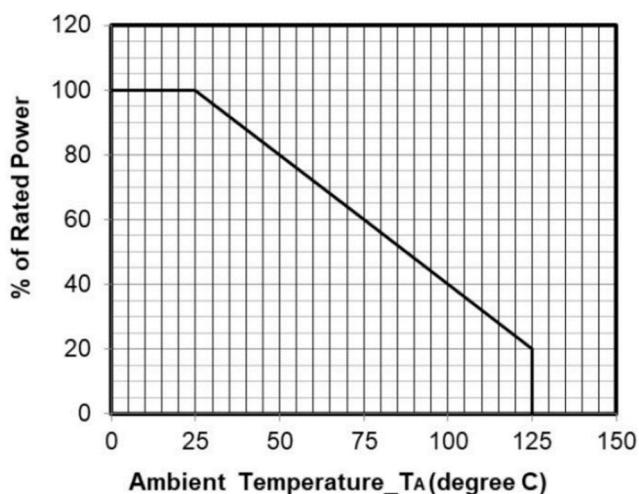


Figure 2: Power Derating Curve

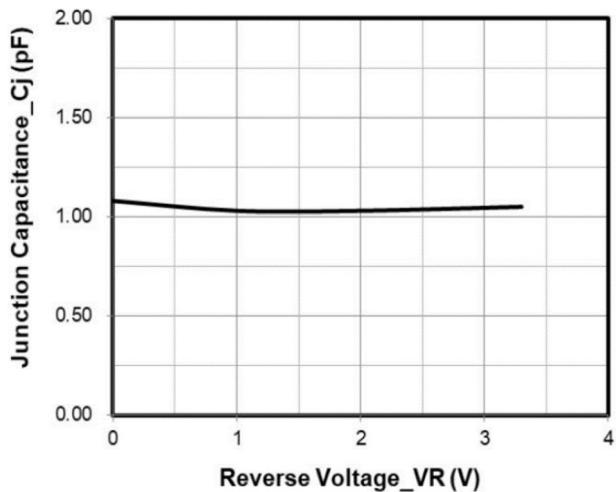


Figure 3: Junction Capacitance vs. Reverse Voltage

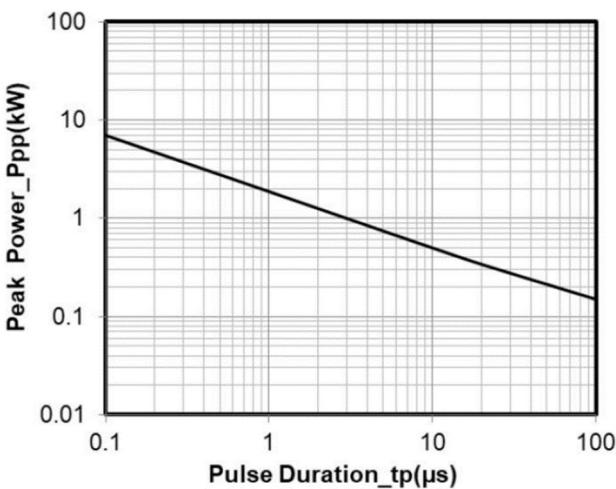


Figure 4: Peak Pulse Power vs. Pulse Time

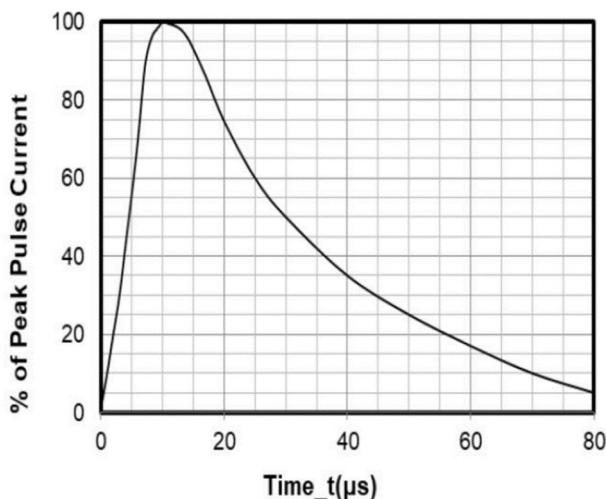


Figure 5: 8 X 20μs Pulse Waveform

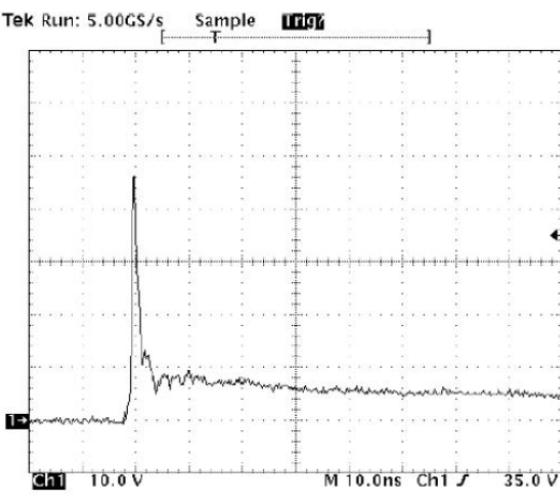
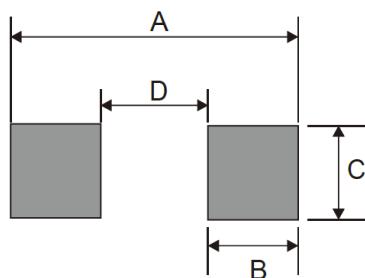


Figure 6: ESD Clamping Voltage  
8 kV Contact per IEC61000-4-2

**Suggested PAD Layout**

Symbol	SOD-323		
	(mm)	(inch)	
A	2.86	0.113	
B	0.63	0.025	
C	0.83	0.033	
D	1.60	0.063	

**Marking Code**

Part Number	Marking Code	
STCS3033BL	R3	

**Ordering information**

Part Number	Package	Base qty	Reel Size	Delivery mode
		(pcs)	(inch)	
STCS3033BL	SOD-323	3,000	7	Tape and reel